

Standard Recovery Diodes

FEATURES

- High surge capability
- Qualified for industrial level
- International standard case DO-205AD
- Both metric and inch threads

TYPICAL APPLICATIONS

- Power supplies
- Machine tools control
- High power drives
- Welders
- Medium traction

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		400	A
	T_{Case}	125	°C
$I_{F(RMS)}$		700	A
	T_{Case}	125	°C
I_{FSM}	50 Hz	10180	A
	60 Hz	11100	A
I^2t	50 Hz	429	kA ² s
	60 Hz	468	kA ² s
V_{DRM}/V_{RRM}		200 to 1600	V
T_J		-40 to 180	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
SERIES	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAX. RE- PETITIVE PEAK AND OFF-STATE VOLTAGE (V)	V_{RSM} , MAX. NON- REPETITIVE PEAK VOLTAGE (V)	I_{DRM}/I_{RRM} , MAX. at T_J = $T_{J(Max.)}$ (mA)
D400/...	18	1800	1900	60
D400/...	20	2000	2100	
D400/...	22	2200	2300	
D400/...	24	2400	2500	
D400/...	26	2600	2700	
D400/...	28	2800	2900	
D400/...	30	3000	3100	

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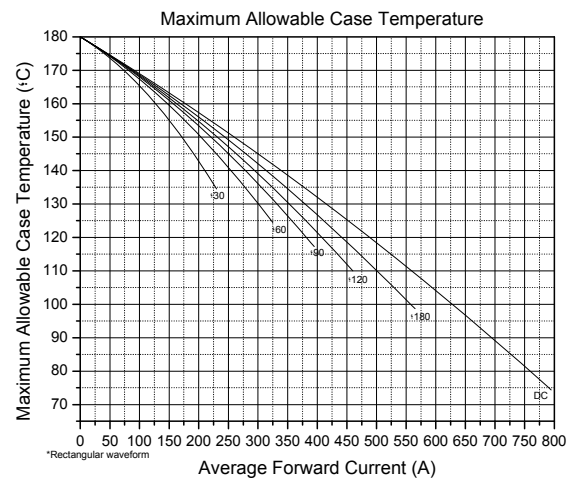
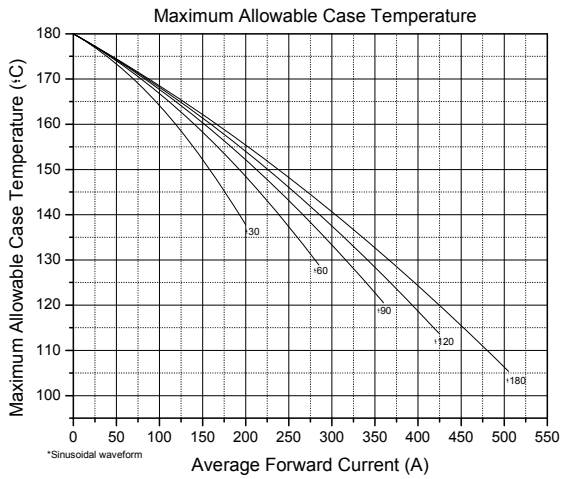
MAXIMUM ALLOWABLE RATINGS						
SYMBOL	DESCRIPTION	TEST CONDITIONS			VALUE	UNITS
$I_{F(AV)}$	Maximum average on-state current at heatsink temperature	180° conduction, half sine wave			400	A
					125	°C
$I_{F(RMS)}$	Maximum RMS on-state current	DC at 25°C heatsink temperature			700	A
I_{FSM}	Maximum peak, one-cycle non-repetitive surge current	t = 10 ms	100% V_{RRM} reapplied	Sinusoidal half wave, initial $T_J = T_J \text{ max.}$	8.56	kA
		t = 8.3 ms			9.33	
		t = 10 ms	No voltage reapplied		10.18	
		t = 8.3 ms			11.1	
I^2t	Maximum I^2t	t = 10 ms	100% V_{RRM} reapplied		303	kA^2s
		t = 8.3 ms			331	
		t = 10 ms	No voltage reapplied		429	
		t = 8.3 ms			468	
$I^2t^{1/2}$	Maximum $I^2t^{1/2}$	t = 0.1 to 10 ms, no voltage reapplied			3800	$kA^2s^{1/2}$
$V_{F(TO)}$	Low level threshold voltage	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J \text{ max.}$			0.97	V
r_F	Low level on-state slope resistance				0.30	mΩ
V_{FM}	Maximum on-state voltage	$I_{pk} = 1256A$, 50Hz half sine pulse, $T_J = T_J \text{ max.}$			1.45	V

THERMAL AND MECHANICAL SPECIFICATIONS				
SYMBOL	DESCRIPTION	TEST CONDITIONS	VALUE	UNITS
T_J	Maximum operating junction temperature	-	-40 to 180	°C
T_{Stg}	Maximum storage temperature	-	-40 to 180	
R_{thJ-hs}	Maximum thermal resistance, junction to heatsink	DC	0.110	°C/W
		180° sine wave	0.120	
		120° rectangular wave	0.130	
R_{thC-hs}	Maximum thermal resistance, case to heat-sink	Mtg. Surface smooth, flat, greased	0.010	
-	Mounting force, ± 10%	-	60	N.m
-	Approximate weight	-	500	g
-	Case style	-	DO-205AD	JEDEC

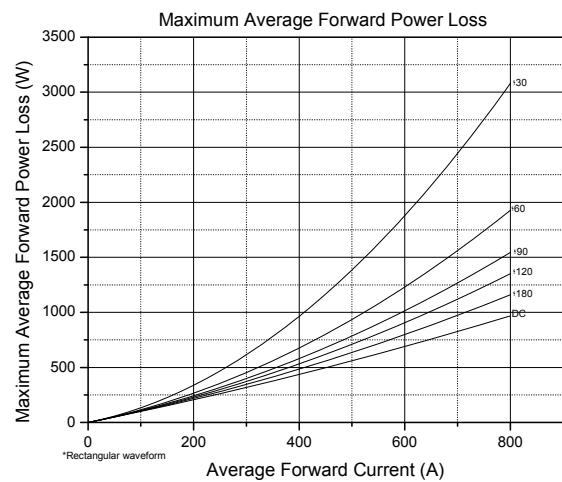
CURRENT FORM FACTOR								
FORM FACTOR	CONDUCTION ANGLE							
		15°	30°	45°	60°	90°	120°	180°
Sine wave		31.956	15.832	10.452	7.721	4.933	3.527	2.468
Rectangular wave		24.000	12.000	8.000	6.000	4.000	3.000	2.000

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CURRENT RATINGS CHARACTERISTICS

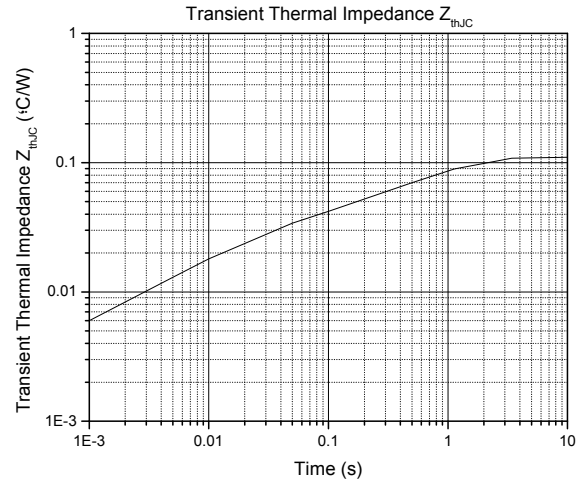
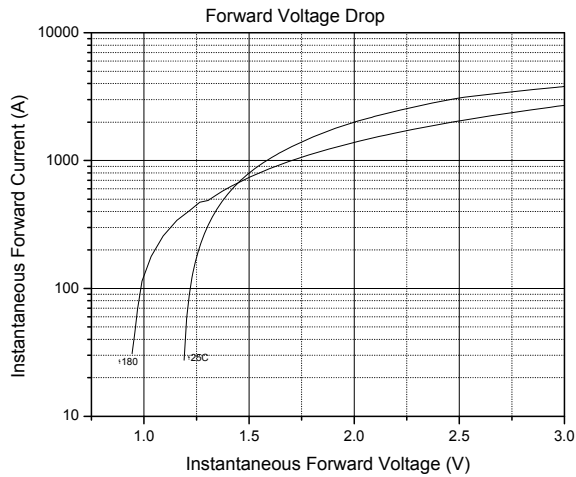


ON-STATE POWER LOSS CHARACTERISTICS

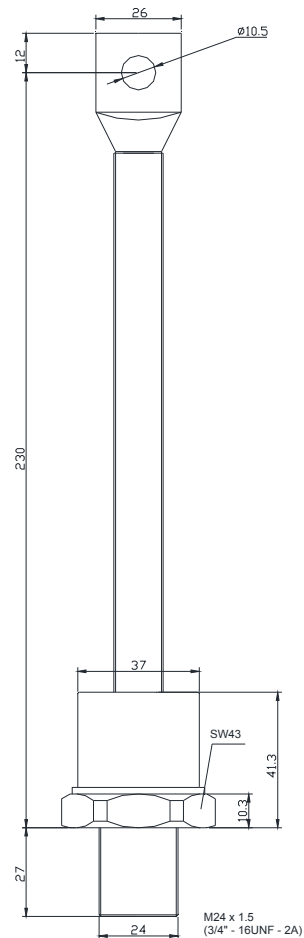


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FORWARD VOLTAGE DROP / THERMAL IMPEDANCE CHARACTERISTICS



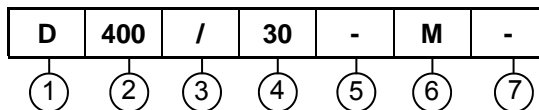
OUTLINE CHARACTERISTICS



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ORDERING INFORMATION

Device code



- | | |
|--|--|
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">1</div> | <ul style="list-style-type: none"> - N = Phase Control Thyristors - F = Fast Thyristors (inverter grade) - D = Normal Recovery Diodes - DF = Fast Recovery Diodes - DD = Module (diode-diode) - DT = Module (diode-thyristor) - TD = Module (thyristor-diode) - TT = Module (thyristor-thyristor) - P = Press-fit diode |
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">2</div> | <ul style="list-style-type: none"> - Average Current Code |
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">3</div> | <ul style="list-style-type: none"> - Essential Part Number |
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">4</div> | <ul style="list-style-type: none"> - Voltage Code x 100 = V_{RRM} |
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">5</div> | <ul style="list-style-type: none"> - Turn-off time (fast thyristors only) - Reverse Recovery Time (fast diodes only) |
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">6</div> | <ul style="list-style-type: none"> - M = Metric Thread - I = Inch Thread |
| <div style="border: 1px solid black; padding: 2px; width: 20px; margin: 5px auto;">7</div> | <ul style="list-style-type: none"> - None = Anode to stud (stud diodes only) - R = Cathode to stud (stud diodes only) |

Disclaimer

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